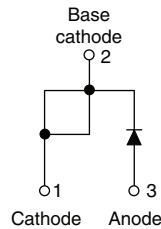


Schottky Rectifier, 10 A


TO-220AC

FEATURES

- 150 °C T_J operation
- TO-220 and D²PAK packages
- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Lead (Pb)-free ("PbF" suffix)
- Designed and qualified for industrial level


RoHS*
COMPLIANT

PRODUCT SUMMARY

$I_{F(AV)}$	10 A
V_R	35/45 V
I_{RM}	15 mA at 125 °C

DESCRIPTION

This Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	10	A
I_{FRM}	$T_C = 135\text{ °C}$	20	
V_{RRM}		35/45	V
I_{FSM}	$t_p = 5\ \mu\text{s}$ sine	1060	A
V_F	10 Apk, $T_J = 125\text{ °C}$	0.57	V
T_J	Range	- 65 to 150	°C

VOLTAGE RATINGS

PARAMETER	SYMBOL	MBR1035PbF	MBR1045PbF	UNITS
Maximum DC reverse voltage	V_R	35	45	V
Maximum working peak reverse voltage	V_{RWM}			

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	$T_C = 135\text{ °C}$, rated V_R	10	A
Peak repetitive forward current	I_{FRM}	Rated V_R , square wave, 20 kHz, $T_C = 135\text{ °C}$	20	
Non-repetitive peak surge current	I_{FSM}	5 μs sine or 3 μs rect. pulse	1060	A
		Surge applied at rated load conditions halfwave, single phase, 60 Hz	150	
Non-repetitive avalanche energy	E_{AS}	$T_J = 25\text{ °C}$, $I_{AS} = 2\text{ A}$, $L = 4\text{ mH}$	8	mJ
Repetitive avalanche current	I_{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical	2	A

* Pb containing terminations are not RoHS compliant, exemptions may apply

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	$V_{FM}^{(1)}$	20 A	$T_J = 25\text{ }^\circ\text{C}$	0.84	V
		10 A	$T_J = 125\text{ }^\circ\text{C}$	0.57	
		20 A		0.72	
Maximum instantaneous reverse current	$I_{RM}^{(1)}$	$T_J = 25\text{ }^\circ\text{C}$	Rated DC voltage	0.1	mA
		$T_J = 125\text{ }^\circ\text{C}$		15	
Threshold voltage	$V_{F(TO)}$	$T_J = T_J$ maximum		0.354	V
Forward slope resistance	r_f			17.6	m Ω
Maximum junction capacitance	C_T	$V_R = 5\text{ }V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 $^\circ\text{C}$		600	pF
Typical series inductance	L_S	Measured from top of terminal to mounting plane		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V_R		10 000	V/ μs

Note

(1) Pulse width < 300 μs , duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction temperature range	T_J			- 65 to 150	$^\circ\text{C}$
Maximum storage temperature range	T_{Stg}			- 65 to 175	
Maximum thermal resistance, junction to case	R_{thJC}	DC operation		2.0	$^\circ\text{C}/\text{W}$
Typical thermal resistance, case to heatsink	R_{thCS}	Mounting surface, smooth and greased (only for TO-220)		0.50	
Approximate weight				2	g
				0.07	oz.
Mounting torque	minimum			6 (5)	kgf · cm (lbf · in)
	maximum			12 (10)	
Marking device		Case style TO-220AC		MBR1045	

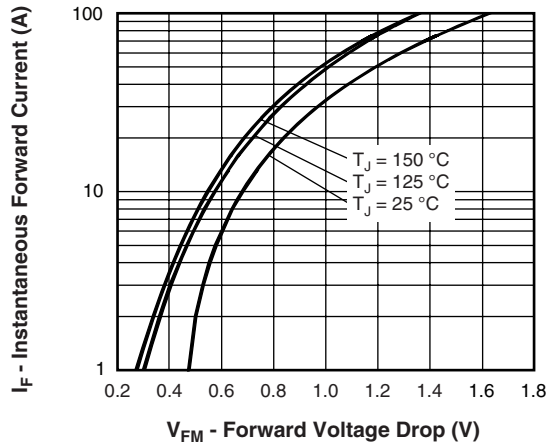


Fig. 1 - Maximum Forward Voltage Drop Characteristics

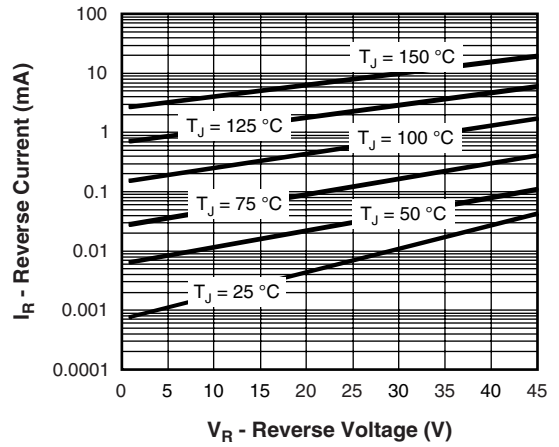


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

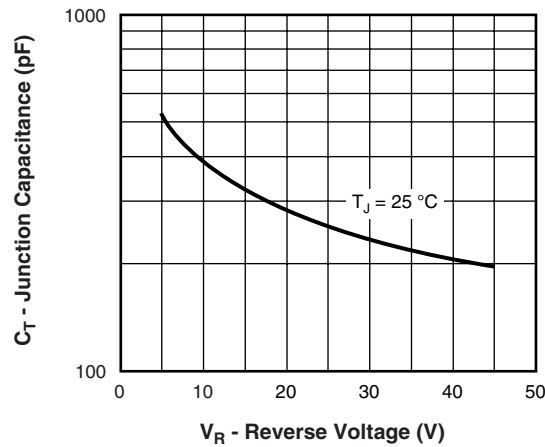


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

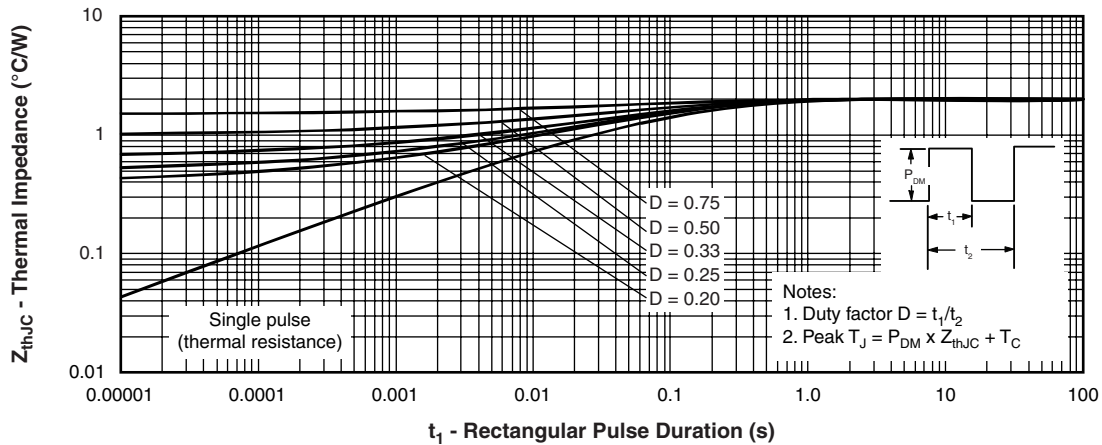


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

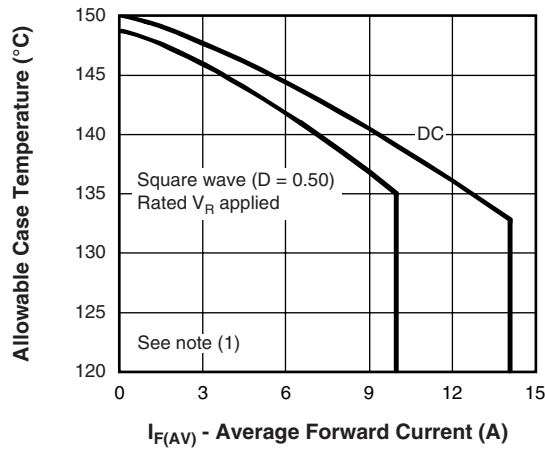


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

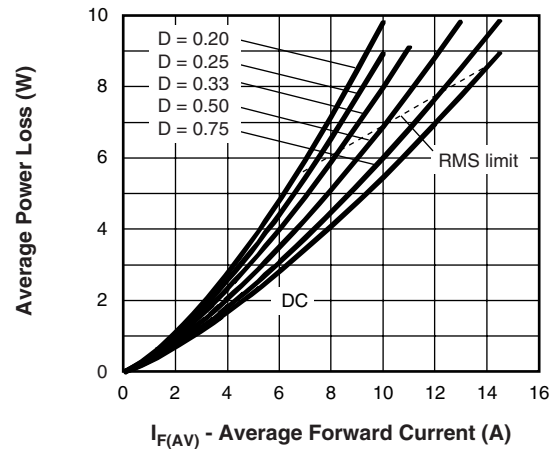


Fig. 6 - Forward Power Loss Characteristics

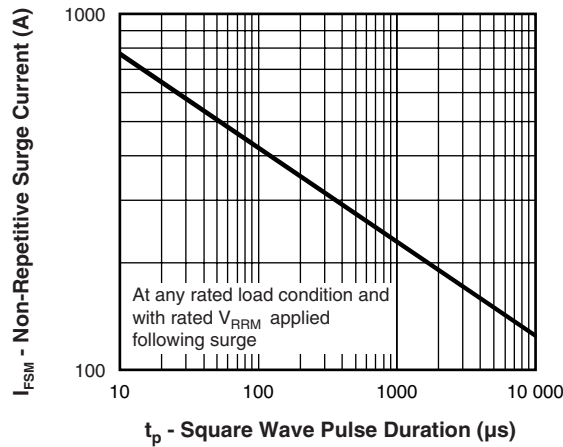


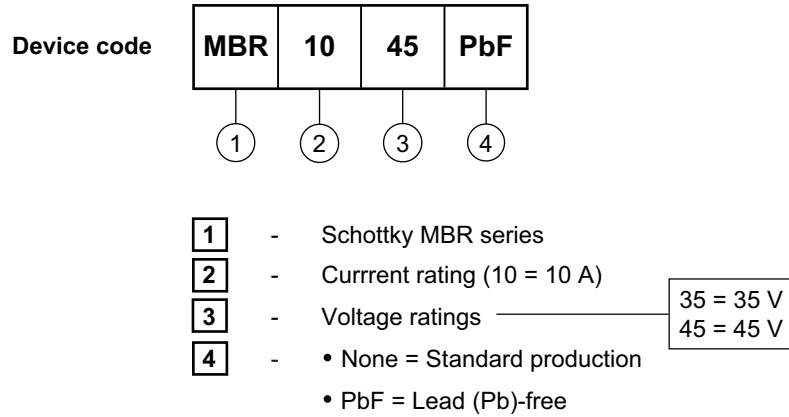
Fig. 7 - Maximum Non-Repetitive Surge Current

Note

- (1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
 Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
 Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = Rated V_R



ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS	
Dimensions	http://www.vishay.com/doc?95221
Part marking information	http://www.vishay.com/doc?95216
SPIICE model	http://www.vishay.com/doc?95293



Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.